## NSN 5962-01-069-8119

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View Online at https://aerobasegroup.com/nsn/5962-01-069-8119
Body Length:
Between 0.750 inches and 0.795 inches
Body Width:
Between 0.245 inches and 0.300 inches
Body Height:
Between 0.120 inches and 0.195 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/storage and programmable and programmed and w/enable and w/open
collector
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Case Outline Source And Designator:
-0-001-ag joint electron device engineering council
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
200.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
07187-aa4009230-140 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer
drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:

**Demilitarization:** Yes - demil/mli

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